# KA2S0765
Fairchild Power Switch(FPS)

Features

• Wide operatimg frequency range up to (150kHz)
• Pulse by pulse over current limiting
• Over load protection
• Over voltage protecton (Min. 23V)
• Internal thermal shutdown function
• Under voltage lockout
• Internal high voltage sense FET
• External sync terminal
• Latch up Mode

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. control IC features a trimmed oscillator, under voltage lock-out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. compared to discrete MOSFET and controller or R_{CC} switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective Monitor power supply.

TO-3P-5L

1

1.DRAIN 2. GND 3. Vcc 4. FB 5. Sync
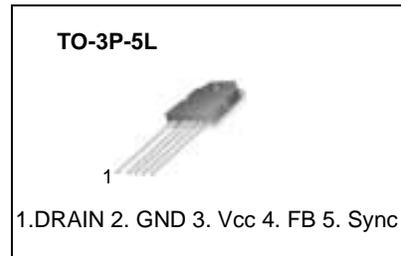
Internal Block Diagram
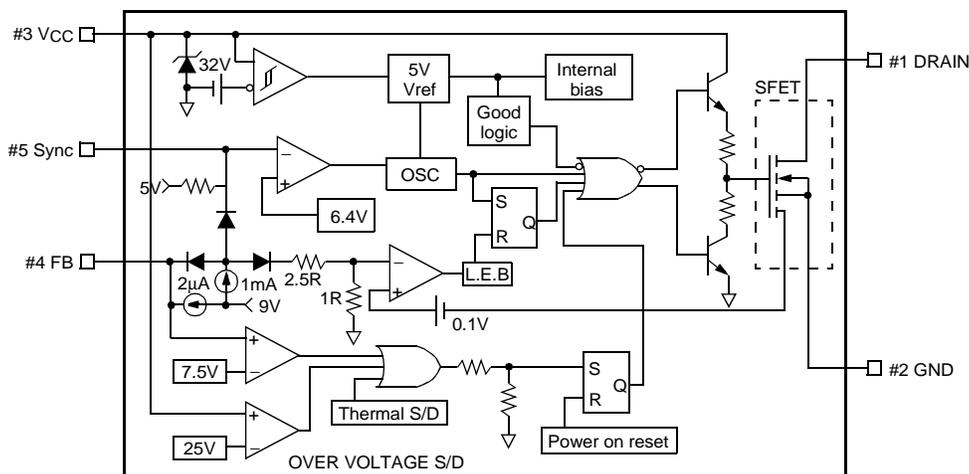
Absolute Maximum Ratings

Characteristic	Symbol	Value	Unit
Maximum Drain voltage [1]	$V_{D,MAX}$	650	V
Drain Gate voltage (R_{GS}=1MΩ)	V_{DGR}	650	V
Gate source (GND) voltage	V_{GS}	$\pm$30	V
Drain current pulsed [2]	I_{DM}	28.0	A_{DC}
Single pulsed avalanche energy [3]	E_{AS}	570	mJ
Continuous drain current (T_C=25°C)	I_D	7.0	A_{DC}
Continuous drain current (T_C=100°C)	I_D	5.6	A_{DC}
Maximum Supply voltage	$V_{CC,MAX}$	30	V
Input voltage range	V_{FB}	−0.3 to V_{SD}	V
Total power dissipation	P_D	140	W
	Derating	1.11	W/°C
Operating ambient temperature	T_A	−25 to +85	°C
Storage temperature	T_{STG}	−55 to +150	°C

Note:

1. T_j=25°C to 150°

2. Repetitive rating: Pulse width limited by maximum junction temperature

3. L=24mH, V_{DD}=50V, R_G=25Ω, starting T_j=25 °C

Electrical Characteristics (SFET part)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
Drain source breakdown voltage	BV$_{DSS}$	V$_{GS}$=0V, I$_D$=50μA	650	-	-	V
Zero gate voltage drain current	I$_{DSS}$	V$_{DS}$=Max., Rating, V$_{GS}$=0V	-	-	50	μA
		V$_{DS}$=0.8Max., Rating, V$_{GS}$=0V, T$_C$=125°C	-	-	200	mA
Static drain source on resistance [note]	R$_{DS(ON)}$	V$_{GS}$=10V, I$_D$=4.0A	-	1.25	1.6	W
Forward transconductance [note]	gfs	V$_{DS}$=15V, I$_D$=4.0A	3.0	-	-	S
Input capacitance	Ciss	V$_{GS}$=0V, V$_{DS}$=25V, f=1MHz	-	1600	-	pF
Output capacitance	Coss		-	310	-	
Reverse transfer capacitance	Crss		-	120	-	
Turn on delay time	td(on)	V$_{DD}$=0.5BV$_{DSS}$, I$_D$=7.0A (MOSFET switching time are essentially independent of operating temperature)	-	25	-	nS
Rise time	tr		-	55	-	
Turn off delay time	td(off)		-	80	-	
Fall time	tf		-	50	-	
Total gate charge (gate-source+gate-drain)	Qg	V$_{GS}$=10V, I$_D$=7.0A, V$_{DS}$=0.5BV$_{DSS}$ (MOSFET switching time are essentially independent of operating temperature)	-	-	72	nC
Gate source charge	Qgs		-	9.3	-	
Gate drain (Miller) charge	Qgd		-	29.3	-	

Note:

Pulse test: Pulse width $\leq$ 300μS, duty cycle $\leq$ 2%

$S = \dfrac{1}{R}$

Electrical Charcteristics (CONTROL part)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start threshold voltage	V_{START}	-	14	15	16	V
Stop threshold voltage	V_{STOP}	After turn on	9	10	11	V
OSCILLATOR SECTION						
Initial accuracy	F_{OSC}	Ta=25°C	18	20	22	kHz
Frequency change with temperature [2]	$\Delta F/\Delta T$	−25°C ≤ Ta ≤ +85°C	-	±5	±10	%
Maximum duty cycle	D_{max}	-	92	95	98	%
FEEDBACK SECTION						
Feedback source current	I_{FB}	Ta=25°C, Vfb=GND	0.7	0.9	1.1	mA
Shutdown Feedback voltage	V_{SD}	-	6.9	7.5	8.1	V
Shutdown delay current	I_{delay}	Ta=25°C, 5V ≤ Vfb ≤ V_{SD}	1.4	1.8	2.2	μA
SYNC. & SOFT START SECTION						
Soft start voltage	V_{SS}	V_{FB}=2V	4.7	5.0	5.3	V
Soft start current	I_{SS}	Sync & S/S=GND	0.8	1.0	1.2	mA
Sync threshold voltage[3]	V_{SYTH}	Vfb=5V	6.0	6.4	6.8	V
REFERENCE SECTION						
Output voltage [1]	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability [1][2]	Vref/ΔT	−25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT (SELF-PROTECTION) SECTION						
Peak Current Limit	I_{OVER}	KA2S0765	4.40	5.00	5.60	A
PROTECTION SECTION						
Thermal shutdown temperature (Tj) [1]	T_{SD}	-	140	160	-	°C
Over voltage protection voltage	V_{OVP}	-	23	25	28	V
TOTAL DEVICE SECTION						
Start Up current	I_{START}	V_{CC}=14V	0.1	0.3	0.55	mA
Operating supply current (control part only)	I_{OP}	Ta=25°C	6	12	18	mA
V_{CC} zener voltage	Vz	I_{CC}=20mA	30	32.5	35	V

Note:

1. These parameters, although guaranteed, are not 100% tested in production

2. These parameters, although guaranteed, are tested in EDS(water test) process

3. The amplitude of the sync. pulse is recommended to be between 2V and 3V for stable sync. function.

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta = 25°C)
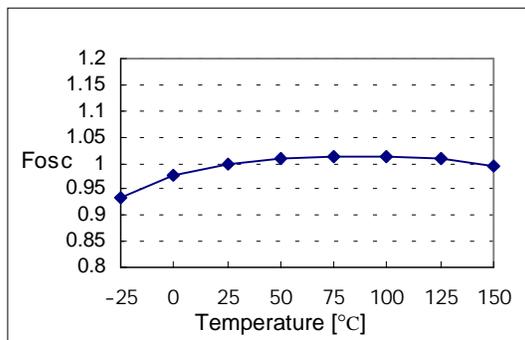
**Figure 1. Operating Frequency**
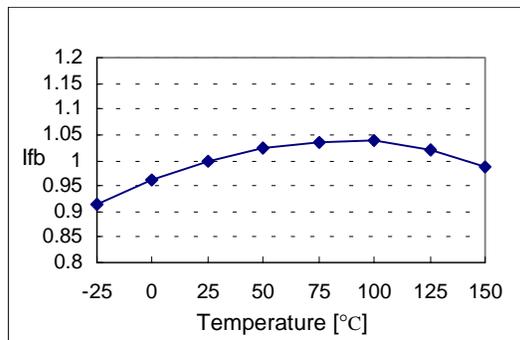
**Figure 2. Feedback Source Current**
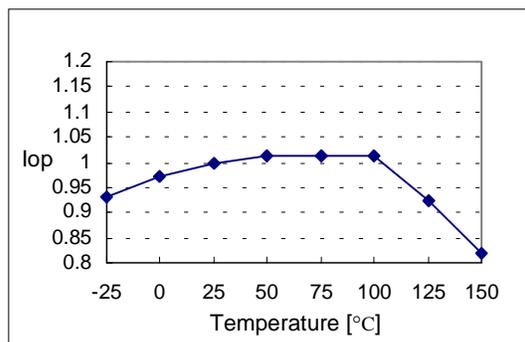
Figure 3. Operating Supply Current
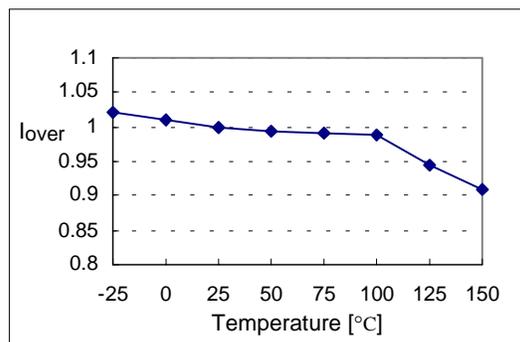
**Figure 4. Peak Current Limit**
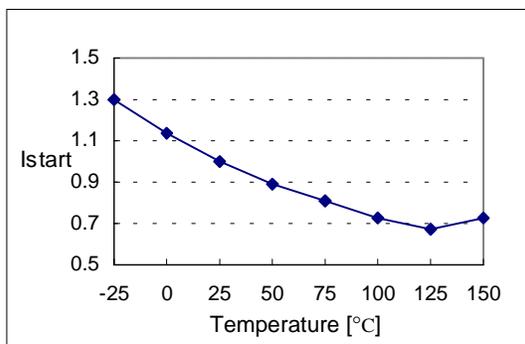
Figure 5. Start up Current
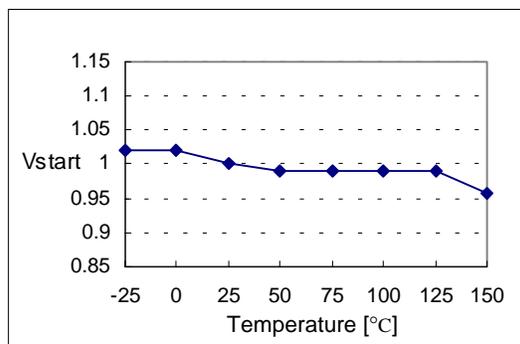
Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)
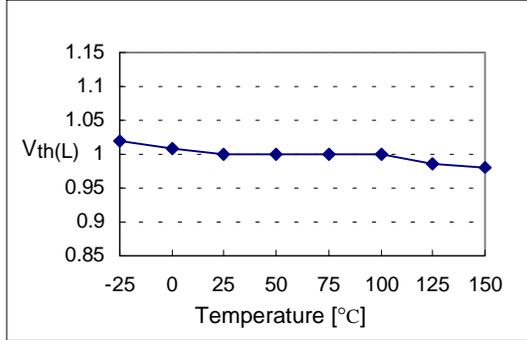
Figure 7. Stop Threshold Voltage
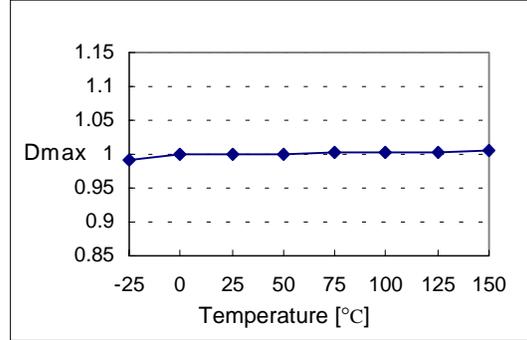
Figure 8. Maximum Duty Cycle
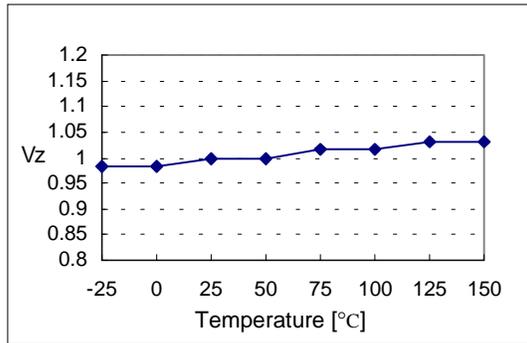
Figure 9. V$_{CC}$ Zener Voltage
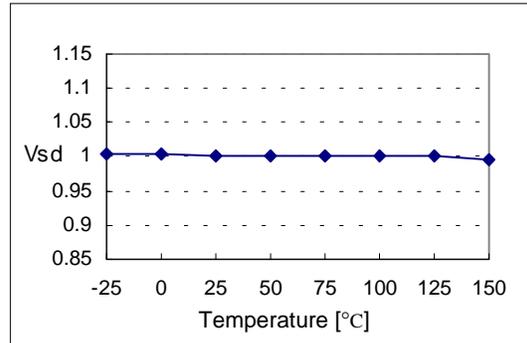
Figure 10. Shutdown Feedback Voltage
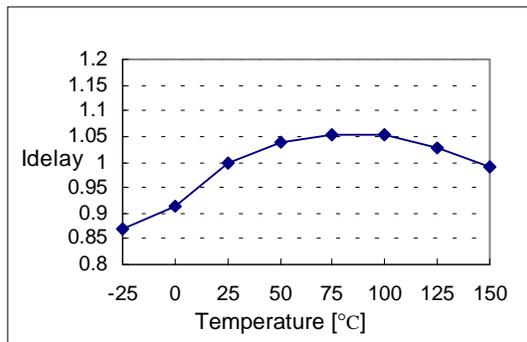
Figure 11. Shutdown Delay Current
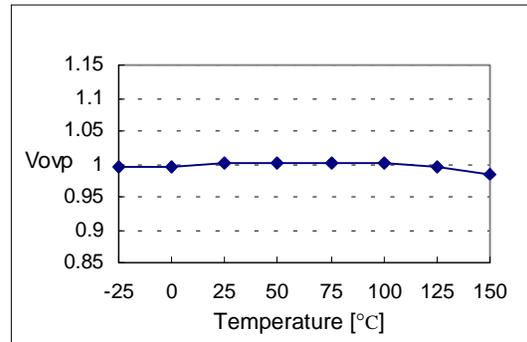
Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)
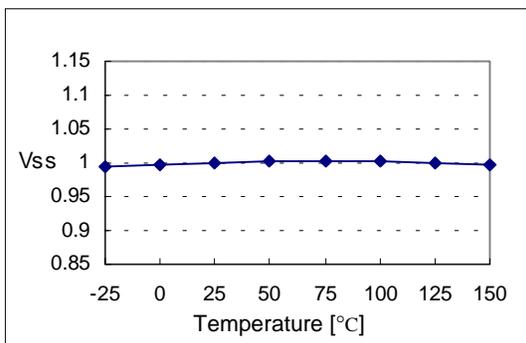
Figure 13. Soft Start Voltage
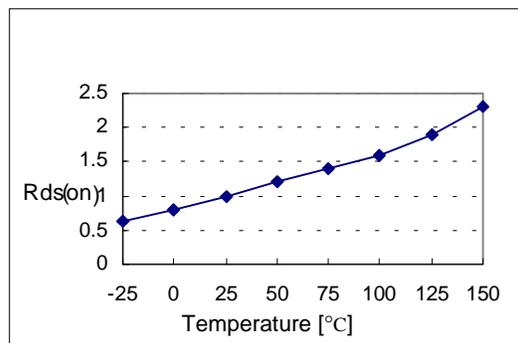
**Figure 14. Static Drain-Source on Resistance**

Package Dimensions

TO-3P-5L

Package Dimensions (Continued)
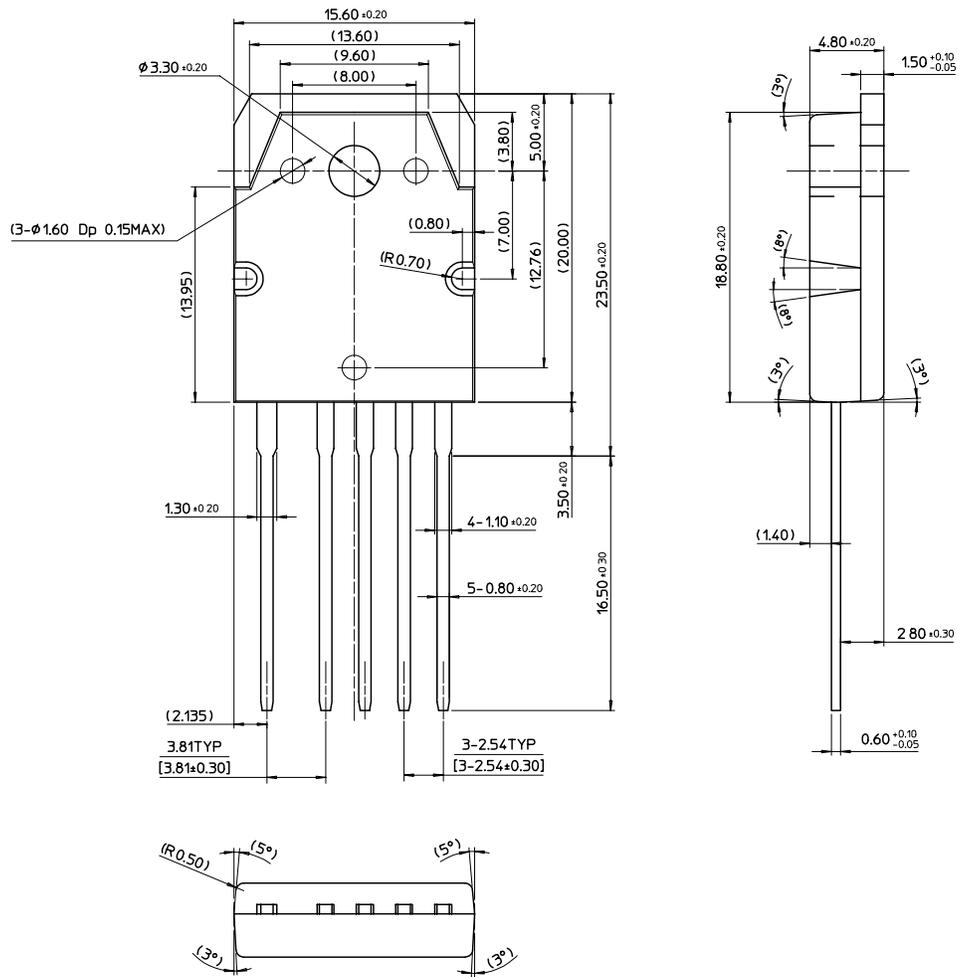
TO-3P-5L (Forming)

Ordering Information

Product Number	Package	Rating	Operating Temperature
KA2S0765-TU	TO-3P-5L	650V,7A	-25°C to +85°C
KA2S0765-YDTU	TO-3P-5L(Forming)		

TU : Non Forming Type
YDTU : Forming Type

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    user.

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    reasonably expected to cause the failure of the life support
    device or system, or to affect its safety or effectiveness.